

# LM4001G THRU LM4007G

## 1.0 AMP SURFACE MOUNT SILICON RECTIFIERS



### FEATURES

- \* Low forward voltage drop
- \* Low leakage current
- \* High reliability

### MECHANICAL DATA

- \* Case: Molded plastic
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Metallurgically bonded construction
- \* Polarity: Color band denotes cathode end
- \* Mounting position: Any

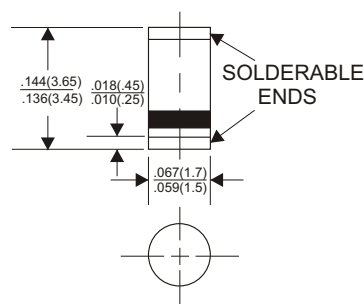
### VOLTAGE RANGE

50 to 1000 Volts

### CURRENT

1.0 Ampere

### DO-213AA



Dimensions in inches and (millimeters)

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.  
Single phase half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

TYPE NUMBER	LM4001G	LM4002G	LM4003G	LM4004G	LM4005G	LM4006G	LM4007G	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current	1.0							A
.375"(9.5mm) Lead Length at Ta=75°C	1.0							A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	25							A
Maximum Instantaneous Forward Voltage at 1.0A	1.1							V
Maximum DC Reverse Current Ta=25°C	5.0							μA
at Rated DC Blocking Voltage Ta=100°C	50							μA
Typical Junction Capacitance (Note 1)	15							pF
Typical Thermal Resistance R JA (Note 2)	75							°C/W
Operating and Storage Temperature Range Tj, Tstg	-65 — +150							°C

#### NOTES:

1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. Thermal Resistance from Junction to Ambient.

## RATING AND CHARACTERISTIC CURVES (LM4001G THRU LM4007G)

FIG.1-TYPICAL FORWARD  
CHARACTERISTICS

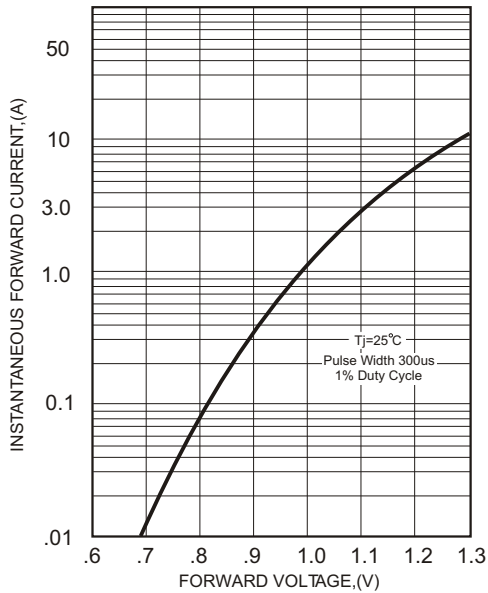


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

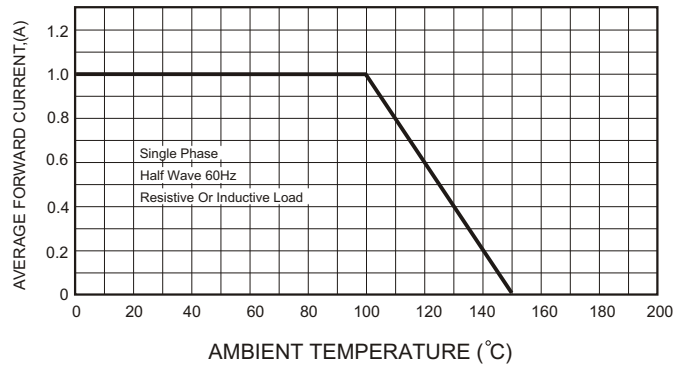


FIG.4-MAXIMUM NON-REPETITIVE FORWARD  
SURGE CURRENT

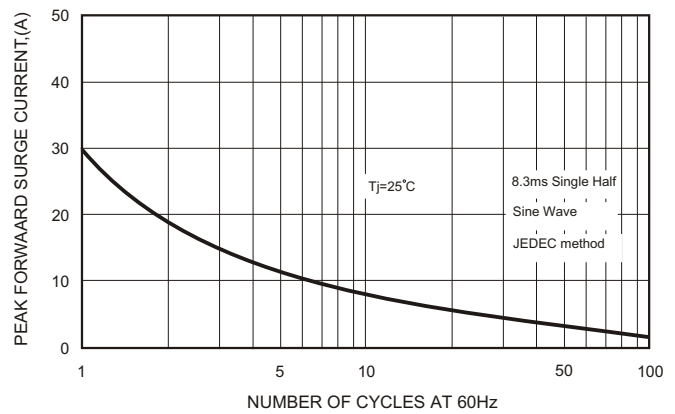


FIG.3 - TYPICAL REVERSE  
CHARACTERISTICS

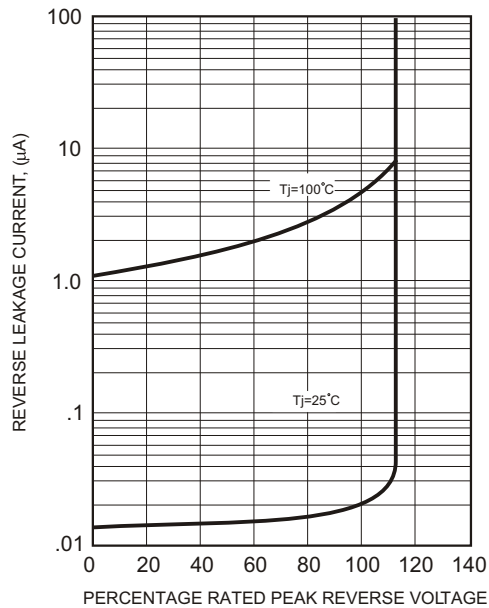


FIG.5-TYPICAL JUNCTION CAPACITANCE

